

208. (New) The method as set forth in claim 205, wherein said second substrate is composed of one of ceramics and gallium-arsenide (GaAs), and further comprising the step of forming a thin glass film on said second substrate, said substrate and said second substrate being electrostatically coupled to each other.

209. (New) The method as set forth in claim 205, wherein said step of removing areas of said substrate includes the step of dipping said substrate into an etching solution having a characteristic of selecting a concentration of said impurities, to thereby solve areas into which said impurities have not been diffused.--

REMARKS

Please charge the deposit account No. 25-0120 in the amount of \$1,782.00 for 6 extra independent claims (above 12 previously paid for, i.e., $6 \times \$84 = \504) and 71 extra claims

(above 69 previously paid for, i.e., $71 \times \$18 = \1278). A duplicate copy of this paper is enclosed for this purpose.

Respectfully submitted,

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December 17, 2001